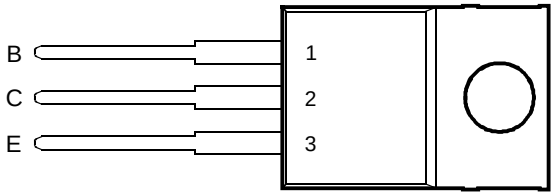
BDW94, BDW94A, BDW94B, BDW94C
PNP SILICON POWER DARLINGTONS

SEPTEMBER 1993 - REVISED MARCH 1997

- **Designed for Complementary Use with BDW93, BDW93A, BDW93B and BDW93C**
- **80 W at 25°C Case Temperature**
- **12 A Continuous Collector Current**
- **Minimum h_{FE} of 750 at 3 V, 5 A**

TO-220 PACKAGE
(TOP VIEW)



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage (I_E = 0)	BDW94	V_{CBO}	-45	V
	BDW94A		-60	
	BDW94B		-80	
	BDW94C		-100	
Collector-emitter voltage (I_B = 0)	BDW94	V_{CEO}	-45	V
	BDW94A		-60	
	BDW94B		-80	
	BDW94C		-100	
Emitter-base voltage		V_{EBO}	-5	V
Continuous collector current		I_C	-12	A
Continuous base current		I_B	-0.3	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 1)		P_{tot}	80	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 2)		P_{tot}	2	W
Operating junction temperature range		T_j	-65 to +150	°C
Storage temperature range		T_{stg}	-65 to +150	°C
Operating free-air temperature range		T_A	-65 to +150	°C

NOTES: 1. Derate linearly to 150°C case temperature at the rate of 0.64 W/°C.
2. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS				MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	I_C = -100 mA	I_B = 0	(see Note 3)	BDW94	-45			V
					BDW94A	-60			
					BDW94B	-80			
					BDW94C	-100			
I_{CEO}	Collector-emitter cut-off current	V_{CB} = -40 V	I_B = 0		BDW94			-1	mA
		V_{CB} = -60 V	I_B = 0		BDW94A			-1	
		V_{CB} = -80 V	I_B = 0		BDW94B			-1	
		V_{CB} = -80 V	I_B = 0		BDW94C			-1	
I_{CBO}	Collector cut-off current	V_{CB} = -45 V	I_E = 0		BDW94			-0.1	mA
		V_{CB} = -60 V	I_E = 0		BDW94A			-0.1	
		V_{CB} = -80 V	I_E = 0		BDW94B			-0.1	
		V_{CB} = -100 V	I_E = 0		BDW94C			-0.1	
		V_{CB} = -45 V	I_E = 0	T_C = 150°C	BDW94			-5	
		V_{CB} = -60 V	I_E = 0	T_C = 150°C	BDW94A			-5	
		V_{CB} = -80 V	I_E = 0	T_C = 150°C	BDW94B			-5	
		V_{CB} = -100 V	I_E = 0	T_C = 150°C	BDW94C			-5	
I_{EBO}	Emitter cut-off current	V_{EB} = -5 V	I_C = 0					-2	mA
h_{FE}	Forward current transfer ratio	V_{CE} = -3 V	I_C = -3 A	(see Notes 3 and 4)		1000			
		V_{CE} = -3 V	I_C = -10 A			100			
		V_{CE} = -3 V	I_C = -5 A			750		20000	
$V_{CE(sat)}$	Collector-emitter saturation voltage	I_B = -20 mA	I_C = -5 A	(see Notes 3 and 4)				-2	V
		I_B = -100 mA	I_C = -10 A					-3	
$V_{BE(sat)}$	Base-emitter saturation voltage	I_B = -20 mA	I_C = -5 A	(see Notes 3 and 4)				-2.5	V
		I_B = -100 mA	I_C = -10 A					-4	
V_{EC}	Parallel diode forward voltage	I_E = -5 A	I_B = 0					-2	V
		I_E = -10 A	I_B = 0					-4	

NOTES: 3. These parameters must be measured using pulse techniques, t_p = 300 µs, duty cycle ≤ 2%.
4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.56	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN
vs
COLLECTOR CURRENT

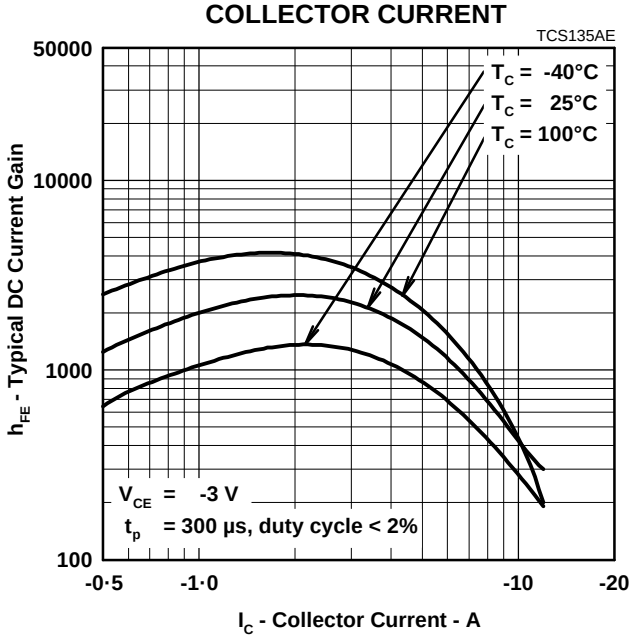


Figure 1.

COLLECTOR-EMITTER SATURATION VOLTAGE
vs
COLLECTOR CURRENT

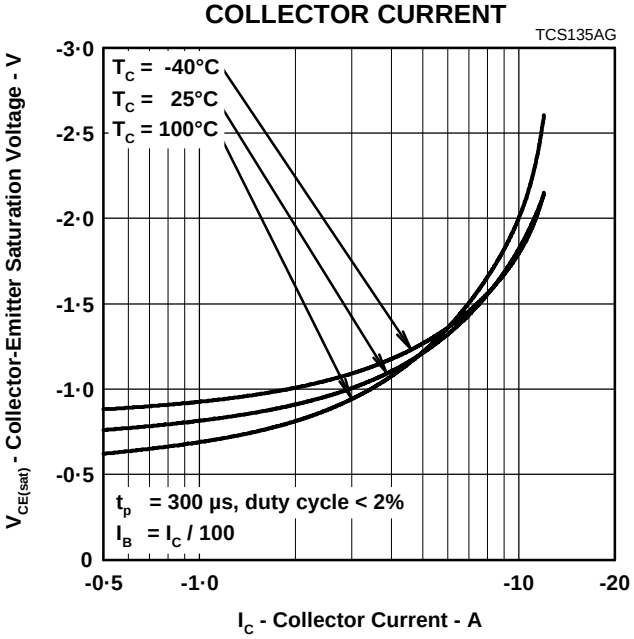


Figure 2.

BASE-EMITTER SATURATION VOLTAGE
vs
COLLECTOR CURRENT

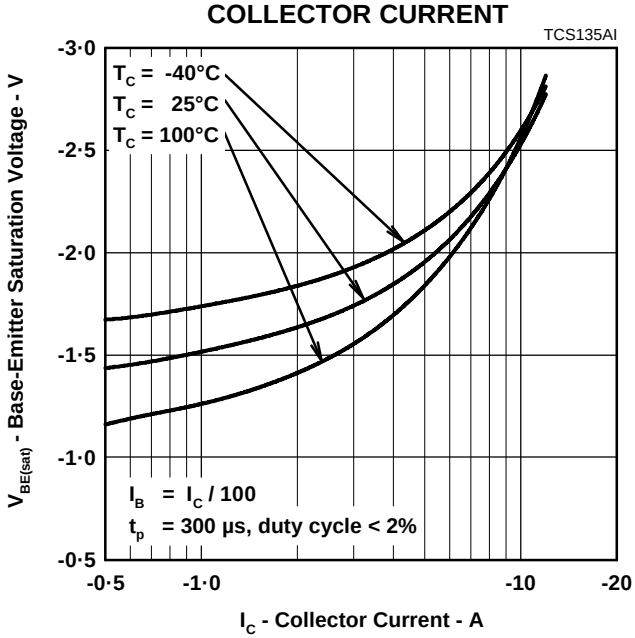


Figure 3.

THERMAL INFORMATION

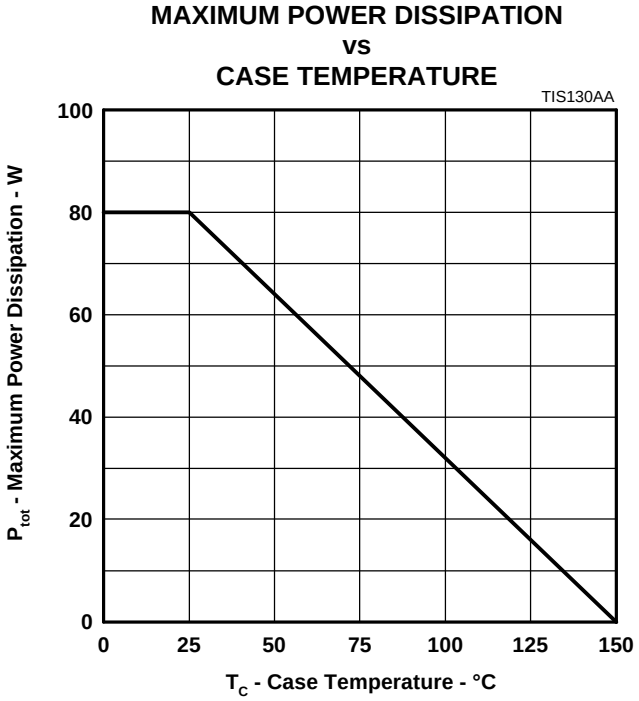
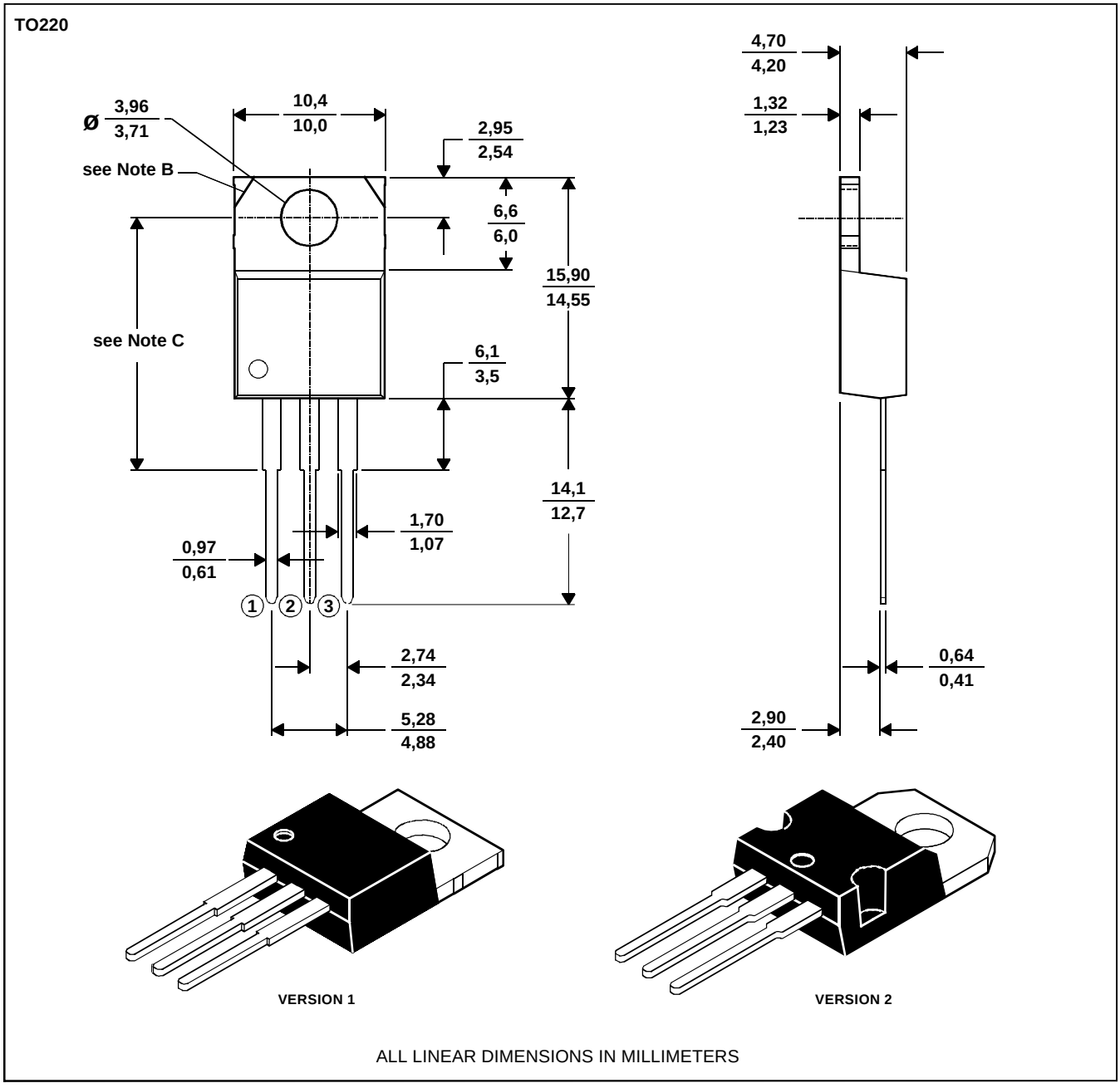


Figure 4.

MECHANICAL DATA

TO-220
3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab. MDXXBE
B. Mounting tab corner profile according to package version.
C. Typical fixing hole centre stand off height according to package version.
Version 1, 18.0 mm. Version 2, 17.6 mm.

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